



#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-30V	$65m\Omega$ @ $V_{GS}$ = -10 $V$	-3.8A
-307	$99m\Omega$ @ $V_{GS}$ = -4.5 $V$	-3.0A

## **Description**

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

## **Applications**

- Backlighting
- Power Management Functions
- DC-DC Converters

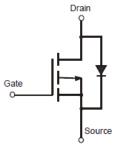
## **Features and Benefits**

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

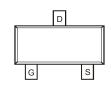
### **Mechanical Data**

- Case: SOT23 (Standard)
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin annealed over Copper leadframe.
  Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)





**Equivalent Circuit** 



Top View Pin Configuration

# Ordering Information (Note 4)

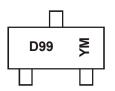
Part Number	Compliance	Case	Packaging
DMP3099L-7	Standard	SOT23 (Standard)	3000/Tape & Reel
DMP3099L-13	Standard	SOT23 (Standard)	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



D99= Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2008		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	V			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

# Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris	tic		Symbol	Value	Units
Drain-Source Voltage		V <sub>DSS</sub>	-30	V	
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Drain Current (Note 5) $V_{GS}$ = -10V Steady $T_A$ = +25°C $T_A$ = +70°C			I <sub>D</sub>	-3.8 -2.9	А
Pulsed Drain Current (Note 6)		I <sub>DM</sub>	-11	Α	

# **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	$P_D$	1.08	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)	$R_{\theta JA}$	115	°C/W
Operating and Storage Temperature Range	$T_{J}, T_{STG}$	-55 to +150	°C



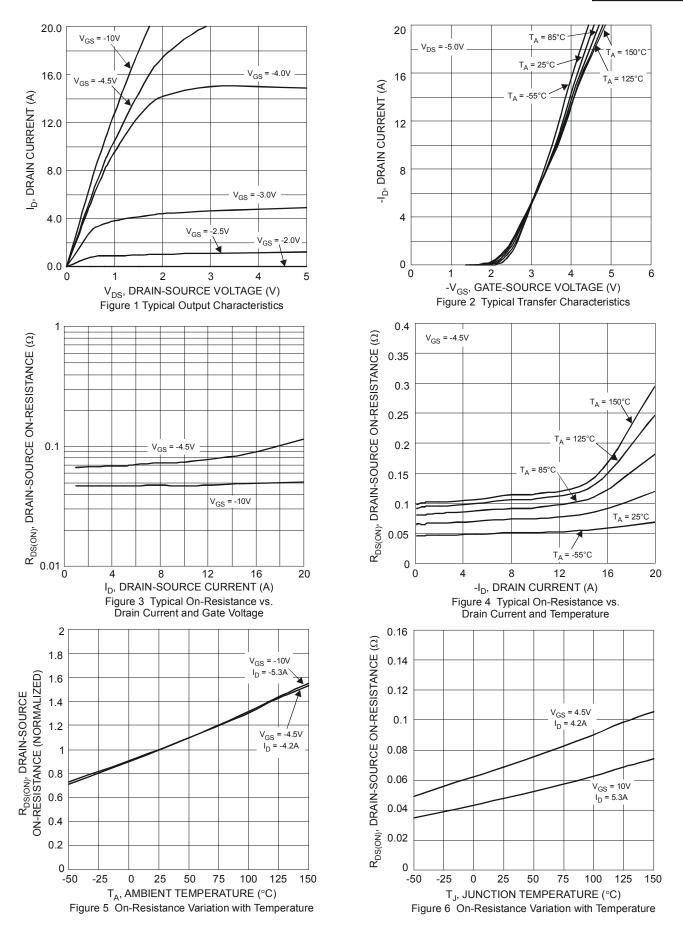
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				•	•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-800	nA	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>		_	±100	nA	$V_{GS}$ = ±20V, $V_{DS}$ = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	_	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	_			65	mΩ	$V_{GS} = -10V, I_D = -3.8A$
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	_	_	99	11177	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -3.0A
Forward Transfer Admittance	Y <sub>fs</sub>	_	3.6	_	S	$V_{DS} = -5V, I_D = -2.7A$
Diode Forward Voltage (Note 6)	$V_{SD}$	_	_	-1.26	V	$V_{GS} = 0V$ , $I_S = -2.7A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>iss</sub>	_	563		pF	V 25V V 2V
Output Capacitance	Coss		48	_	pF	V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V, -f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	41	_	pF T = T.UMH2	
Gate Resistance	$R_G$		10.3	_	Ω	$V_{GS} = 0V V_{DS} = 0V, f = 1MHz$
SWITCHING CHARACTERISTICS (Note 8)						
Total Gate Charge	$Q_{g}$	_	5.2	_		$V_{DS} = -15V$ , $V_{GS} = -4.5V$ , $I_{D} = -3.8A$
-		_	11	_	nC	V 4514 V 4014
Gate-Source Charge	$Q_{gs}$	_	1.7	_		$V_{DS} = -15V, V_{GS} = -10V,$ $I_{D} = -3.8A$
Gate-Drain Charge	$Q_{gd}$		1.9	_		ID = -3.6A
Turn-On Delay Time	t <sub>d(on)</sub>	_	4.8	_		
Rise Time	t <sub>r</sub>	_	5.0	_	200	$V_{DS} = -15V, V_{GS} = -10V,$
Turn-Off Delay Time	t <sub>d(off)</sub>	_	31	_	ns	$I_D = -1A, R_G = 6.0\Omega$
Fall Time	t <sub>f</sub>		15			

Notes:

<sup>5.</sup> Device mounted on FR-4 PCB on 2 oz., 0.5 in.  $^2$  copper pads and t  $\leq$ 5 sec. 6. Pulse width  $\leq$ 10 $\mu$ S, Duty Cycle  $\leq$ 1%. 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.







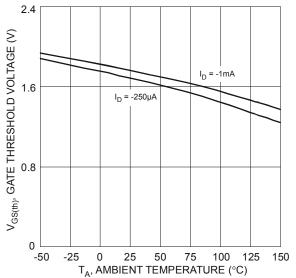
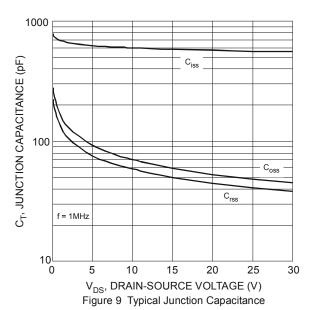
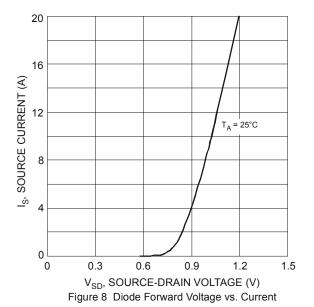


Figure 7 Gate Threshold Variation vs. Ambient Temperature





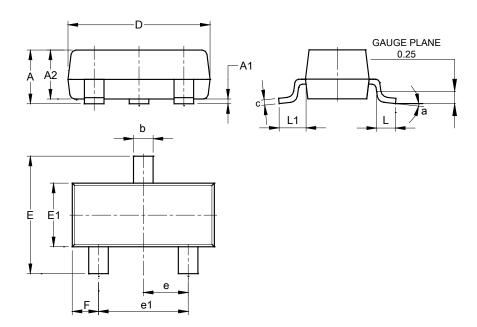
10 9 V<sub>DS</sub> = 15V I<sub>D</sub> = 3.8A  $V_{\rm GS}$  GATE THRESHOLD VOLTAGE (V) 7 4 3 2 0 0 2 6 8 10 12  $\mathbf{Q_g}$ , TOTAL GATE CHARGE (nC) Figure 10 Gate Charge



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23 (Standard)

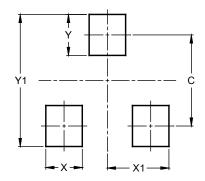


SOT23 (Standard)							
Dim	Min	Max	Тур				
Α	0.90	1.15	1.025				
A1	0.00	0.10	0.05				
A2	0.85	1.10	0.975				
b	0.30	0.51	0.40				
С	0.080	0.202	0.11				
D	2.80	3.00	2.90				
Е	2.25	2.55	2.40				
E1	1.20	1.40	1.30				
е	0.89	1.03	0.915				
e1	1.78	2.05	1.83				
F	0.40	0.60	0.535				
L1	0.45	0.61	0.55				
L	0.25	0.55	0.40				
а	0°	8°					
All Dimensions in mm							

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23 (Standard)



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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